

Product Specification

Microprocessor Division

DESCRIPTION

The Signetics SCN8031AH/SCN8051AH is a high-performance microcontroller fabricated using the Signetics highly reliable +5V, depletion-load, N-channel, silicon-gate, N500 MOS process technology. It provides the hardware features, architectural enhancements and instructions that are necessary to make it a powerful and cost-effective controller for applications requiring up to 64K bytes of program memory and/or up to 64K bytes of data storage.

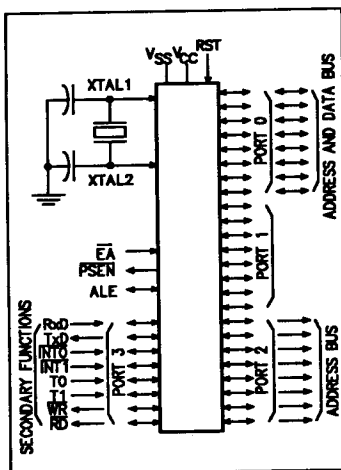
The SCN8051AH contains a 4K X 8 read-only program memory, a 128 X 8 read/write data memory, 32 I/O lines, two 16-bit timer/counters, a five-source two-priority-level nested interrupt structure, a serial I/O port for either multiprocessor communications, I/O expansion, or full-duplex UART, and on-chip oscillator and clock circuits. The SCN8031AH is identical, except that it lacks the program memory. For systems that require extra capability, the SCN8051AH can be expanded using standard TTL compatible memories and byte oriented peripheral controllers.

The SCN8051AH microcontroller, like its SCN8048 predecessor, is efficient both as a controller and as an arithmetic processor. It has extensive facilities for binary and BCD arithmetic and excels in bit-handling capabilities. Efficient use of program memory results from an instruction set consisting of 44% one-byte, 41% two-byte, and 15% three-byte instructions. With a 12MHz crystal, 58% of the instructions execute in 1 μ s, 40% in 2 μ s and multiply and divide require only 4 μ s.

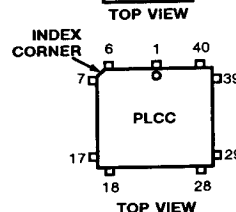
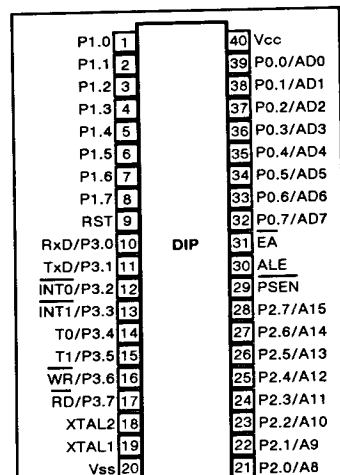
FEATURES

- Reduced supply current
- 4K X 8 ROM (SCN8051AH)
- 128 X 8 RAM
- Four 8-bit ports, 32 I/O lines
- Two 16-bit timer/event counters
- High-performance full-duplex serial channel
- External memory expandable to 128K
- Boolean processor
- Industry standard 8051 architecture:
 - Non-paged jumps
 - Direct addressing
 - Four 8-register banks
 - Stack depth up to 128-bytes
 - Multiply, divide, subtract, compare
- Most instructions execute in 1 μ s
- 4 μ s multiply and divide

LOGIC SYMBOL



PIN CONFIGURATION

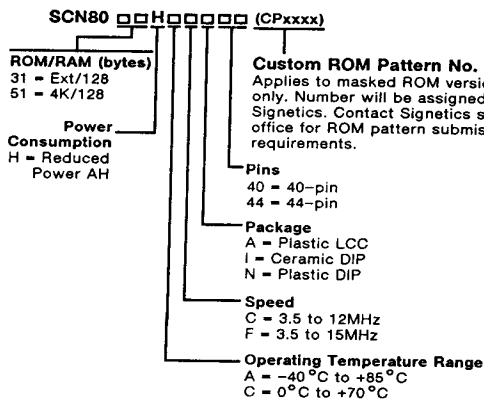


Pin	Function	Pin	Function
1	NC	23	NC
2	P1.0	24	P2.0/A8
3	P1.1	25	P2.1/A9
4	P1.2	26	P2.2/A10
5	P1.3	27	P2.3/A11
6	P1.4	28	P2.4/A12
7	P1.5	29	P2.5/A13
8	P1.6	30	P2.6/A14
9	P1.7	31	P2.7/A15
10	RST	32	PSEN
11	RxD/P3.0	33	ALE
12	NC	34	NC
13	TxD/P3.1	35	EA
14	INT0/P3.2	36	P0.7/AD7
15	INT1/P3.3	37	P0.6/AD6
16	T0/P3.4	38	P0.5/AD5
17	T1/P3.5	39	P0.4/AD4
18	WR/P3.6	40	P0.3/AD3
19	RD/P3.7	41	P0.2/AD2
20	XTAL2	42	P0.1/AD1
21	XTAL1	43	P0.0/AD0
22	Vss	44	Vcc

Single-Chip 8-Bit Microcontroller

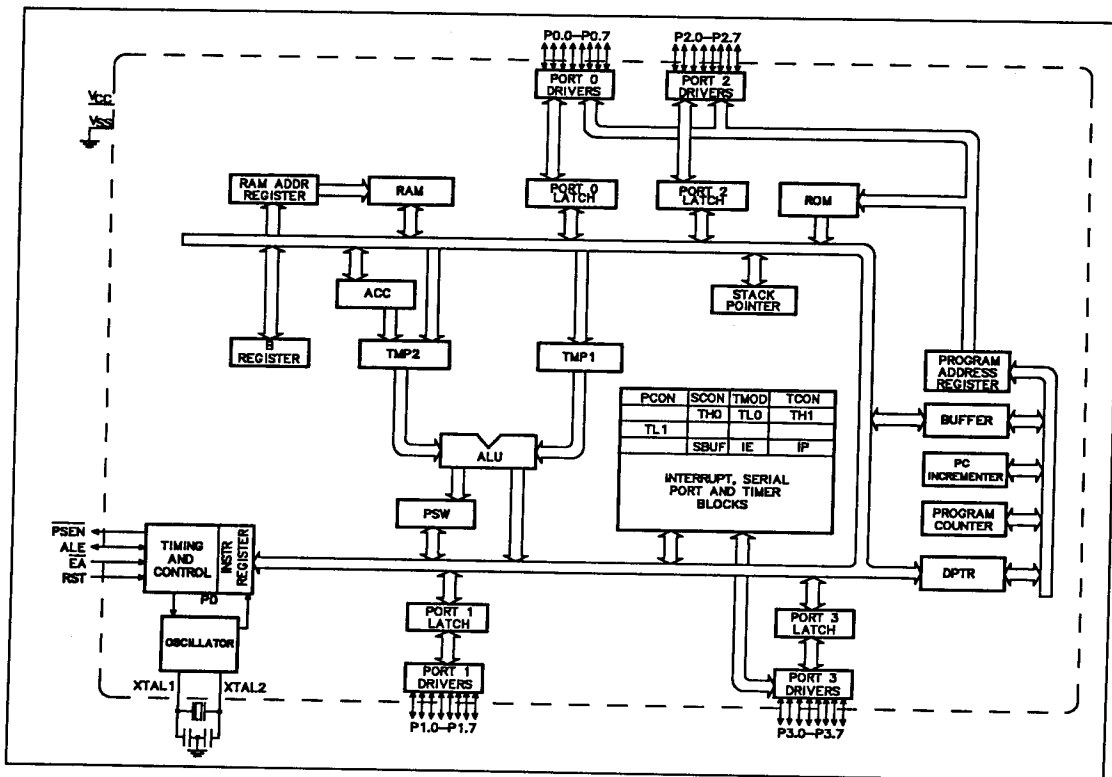
SCN8031AH/SCN8051AH

ORDERING INFORMATION



PART NUMBER SELECTION			
ROMless	ROM	Temperature and Package	Frequency
SCN8031HACN40	SCN8051HACN40	-40 to +85°C plastic DIP	3.5 to 12MHz
SCN8031HCCN40	SCN8051HCCN40	0 to +70°C plastic DIP	3.5 to 12MHz
SCN8031HCFN40	SCN8051HCFN40	0 to +70°C plastic DIP	3.5 to 15MHz
SCN8031HAFN40	SCN8051HAFN40	-40 to +85°C plastic PLCC	3.5 to 15MHz
SCN8031HCCA44	SCN8051HCCA44	0 to +70°C plastic PLCC	3.5 to 12MHz
SCN8031HACA44	SCN8051HACA44	-40 to +85°C plastic PLCC	3.5 to 12MHz
SCN8031HCFA44	SCN8051HCFA44	0 to +70°C plastic PLCC	3.5 to 15MHz
SCN8031HAFA44	SCN8051HAFA44	-40 to +85°C plastic PLCC	3.5 to 15MHz

BLOCK DIAGRAM



Single-Chip 8-Bit Microcontroller

SCN8031AH/SCN8051AH

PIN DESCRIPTION

MNEMONIC	PIN NO.		TYPE	NAME AND FUNCTION
	DIP	LCC		
V _{SS}	20	22	I	Ground: 0V reference.
V _{CC}	40	44	I	Power Supply: This is the power supply voltage for normal, idle, and power-down operation.
P0.0–P0.7	39–32	43–36	I/O	Port 0: Port 0 is an open-drain, bidirectional I/O port. Port 0 pins that have 1s written to them float and can be used as high-impedance inputs. Port 0 is also the multiplexed low-order address and data bus during accesses to external program and data memory. In this application, it uses strong internal pullups when emitting 1s.
P1.0–P1.7	1–8	2–9	I/O	Port 1: Port 1 is an 8-bit bidirectional I/O port with internal pull-ups. Port 1 pins that have 1s written to them are pulled high by the internal pullups and can be used as inputs. As inputs, port 1 pins that are externally pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I _{IL}).
P2.0–P2.7	21–28	24–31	I/O	Port 2: Port 2 is an 8-bit bidirectional I/O port with internal pull-ups. Port 2 pins that have 1s written to them are pulled high by the internal pullups and can be used as inputs. As inputs, port 2 pins that are externally being pulled low will source current because of the internal pullups. (See DC Electrical Characteristics: I _{IL}). Port 2 emits the high-order address byte during fetches from external program memory and during accesses to external data memory that use 16-bit addresses (MOVX @DPTR). In this application, it uses strong internal pull-ups when emitting 1s. During accesses to external data memory that use 8-bit addresses (MOVX @Ri), port 2 emits the contents of the P2 special function register.
P3.0–P3.7	10–17	11, 13–19	I/O	Port 3: Port 3 is an 8-bit bidirectional I/O port with internal pullups. Port 3 pins that have 1s written to them are pulled high by the internal pullups and can be used as inputs. As inputs, port 3 pins that are externally being pulled low will source current because of the pull-ups. (See DC Electrical Characteristics: I _{IL}). Port 3 is also used for the special features listed below:
	10	11	I	RxD (P3.0): Serial input port
	11	13	O	TxD (P3.1): Serial output port
	12	14	I	INT0 (P3.2): External interrupt
	13	15	I	INT1 (P3.3): External interrupt
	14	16	I	T0 (P3.4): Timer 0 external input
	15	17	I	T1 (P3.5): Timer 1 external input
	16	18	O	WR (P3.6): External data memory write strobe
	17	19	O	RD (P3.7): External data memory read strobe
RST	9	10	I	Reset: A high on this pin for two machine cycles while the oscillator is running, resets the device. An internal diffused resistor to V _{SS} permits a power-on reset using only an external capacitor to V _{CC} .
ALE	30	33	I/O	Address Latch Enable: Output pulse for latching the low byte of the address during an access to external memory. In normal operation, ALE is emitted at a constant rate of 1/6 the oscillator frequency, and can be used for external timing or clocking. Note that one ALE pulse is skipped during each access to external data memory.
PSEN	29	32	O	Program Store Enable: The read strobe to external program memory. When the device is executing code from external program memory, PSEN is activated twice each machine cycle, except that two PSEN activations are skipped during each access to external data memory. PSEN is not activated during fetches from internal program memory.
EA	31	35	I	External Access Enable: EA must be externally held low to enable the device to fetch code from external program memory locations 0000H and 0FFFH. If EA is held high, the device executes from internal program memory unless the program counter contains an address greater than 0FFFH.
XTAL1	19	21	I	Crystal 1: Input to the inverting oscillator amplifier.
XTAL2	18	20	O	Crystal 2: Output from the inverting oscillator amplifier and input to the internal clock generator circuits.

Single-Chip 8-Bit Microcontroller

SCN8031AH/SCN8051AH

OSCILLATOR CHARACTERISTICS

XTAL1 and XTAL2 are the input and output, respectively, of an inverting amplifier. The pins can be configured for use as an on-chip oscillator, as shown in the logic symbol, page 1.

To drive the device from an external clock source, XTAL2 should be driven while XTAL1 is left unconnected. There are no requirements on the duty cycle of the external clock signal, because the input to the internal clock circuitry is through a divide-by-two flip-flop. However, minimum and maximum high and low times specified in the data sheet must be observed.

DESIGN CONSIDERATIONS

At power-on, the voltage on VCC and RST should come up at the same time for a proper start-up.

ABSOLUTE MAXIMUM RATINGS^{1, 2, 3}

PARAMETER	RATING	UNIT
Storage temperature range	-65 to +150	°C
All voltages with respect to ground	-0.5 to +7.0	V
Power dissipation	1.0	W

DC ELECTRICAL CHARACTERISTICS T_A = 0°C to +70°C, V_{CC} = 4.5 to 5.5V, V_{SS} = 0V^{4, 5}

Symbol	Parameter	Test Conditions	Limits		Unit
			Min	Max	
V _{IL}	Input low voltage		-0.5	0.8	V
V _{IH}	Input high voltage, except RST and XTAL2		2	V _{CC} +0.5	V
V _{IH1}	Input high voltage to RST for reset, XTAL2	XTAL1 to V _{SS}	2.5	V _{CC} +0.5	V
V _{OL}	Output low voltage, ports 1, 2, 3 ⁶	I _{OL} = 1.6mA		0.45	V
V _{OL1}	Output low voltage, port 0, ALE, PSEN ⁶	I _{OL} = 3.2mA		0.45	V
V _{OH}	Output high voltage, ports 1, 2, 3	I _{OH} = -80μA	2.4		V
V _{OH1}	Output high voltage port 0, ALE, PSEN) ³	I _{OH} = -400μA	2.4		V
I _{IL}	Logical 0 input current, ports 1, 2, 3	V _{IN} = 0.45V		-500	μA
I _{IH1}	Input high current to RST for reset	V _{IN} < V _{CC} - 1.5V		500	μA
I _{LI}	Input leakage current, port 0, EA	0.45 < V _{IN} < V _{CC}		±10	μA
I _{IL2}	Logical 0 input current for XTAL2	XTAL1 = V _{SS} , V _{IN} = 0.45V		-3.2	mA
I _{CC}	Power supply current:	All outputs disconnected and EA = V _{CC}		125	mA
C _{IO}	Pin capacitance			10	pF

T_A = -40°C to +85°C - Extended temperature range - SCN8051HAC only

V _{IH}	Input high voltage, except RST and XTAL2		2.2	V _{CC} +0.5	V
V _{IH1}	Input high voltage to RST for reset, XTAL2	XTAL1 to V _{SS}	2.7		V
I _{CC}	Power supply current:	All outputs disconnected and EA = V _{CC}		175	mA

NOTES:

- Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any conditions other than those described in the AC and DC Electrical Characteristics section of this specification is not implied.
- For operating at elevated temperatures, the device must be derated based on +150°C maximum junction temperature.
- This product includes circuitry specifically designed for the protection of its internal devices from the damaging effects of excessive static charge. Nonetheless, it is suggested that conventional precautions be taken to avoid applying voltages greater than the rated maxima.
- Parameters are valid over operating temperature range unless otherwise specified.
- All voltage measurements are referenced to ground. For testing, all input signals swing between 0.45V and 2.4V with a transition time of 20ns maximum. All time measurements are referenced at input voltages of 0.8V and 2.0V and at output voltages of 0.8V and 2.0V as appropriate.
- V_{OL} is degraded when the device rapidly discharges external capacitance. This AC noise is most pronounced during emission of address data. When using external memory, locate the latch or buffer as close to the device as possible.

Datum	Emitting	Degraded	
Address	Ports	I/O Lines	V _{OL} (Peak Max)
Write Data	P2, P0	P1, P3	0.8V
	P0	P1, P3, ALE	0.8V
- CL = 100pF for port 0, ALE and PSEN outputs; CL = 80pF for all other ports.

Single-Chip 8-Bit Microcontroller

SCN8031AH/SCN8051AH

AC ELECTRICAL CHARACTERISTICS $T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$ or -40°C to $+85^\circ\text{C}$, $V_{CC} = 5V \pm 20\%$, $V_{SS} = 0V^{1, 2}$

SYMBOL	FIGURE	PARAMETER	12MHz CLOCK		VARIABLE CLOCK		UNIT
			Min	Max	Min	Max	
Program Memory							
$1/t_{CLCL}$	1	Oscillator frequency: Speed Versions SCN8051 C SCN8051 F			3.5 3.5	12 15	MHz
t_{LHLL}	1	ALE pulse width	127		$2t_{CLCL}-40$		ns
t_{AVLL}	1	Address valid to ALE low	43		$t_{CLCL}-40$		ns
t_{LLAX}	1	Address hold after ALE low	48		$t_{CLCL}-35$		ns
t_{LLIV}	1	ALE low to valid instruction in		233		$4t_{CLCL}-100$	ns
t_{LLPL}	1	ALE low to $\overline{\text{PSEN}}$ low	58		$t_{CLCL}-25$		ns
t_{PLPH}	1	$\overline{\text{PSEN}}$ pulse width	215		$3t_{CLCL}-35$		ns
t_{PLIV}	1	$\overline{\text{PSEN}}$ low to valid instruction in		125		$3t_{CLCL}-125$	ns
t_{PXIX}	1	Input instruction hold after $\overline{\text{PSEN}}$	0		0		ns
t_{PXIZ}	1	Input instruction float after $\overline{\text{PSEN}}$		63		$t_{CLCL}-20$	ns
t_{AVIV}	1	Address to valid instruction in		302		$5t_{CLCL}-115$	ns
t_{PLAZ}	1	$\overline{\text{PSEN}}$ low to address float		20		20	ns
t_{PXAV}	1	$\overline{\text{PSEN}}$ to address valid	75		$t_{CLCL}-8$		ns
Data Memory							
t_{RLRH}	2, 3	$\overline{\text{RD}}$ pulse width	400		$6t_{CLCL}-100$		ns
t_{WLWH}	2, 3	$\overline{\text{WR}}$ pulse width	400		$6t_{CLCL}-100$		ns
t_{RLDV}	2, 3	$\overline{\text{RD}}$ low to valid data in		252		$5t_{CLCL}-165$	ns
t_{RHDX}	2, 3	Data hold after $\overline{\text{RD}}$	0		0		ns
t_{RHDZ}	2, 3	Data float after $\overline{\text{RD}}$		97		$2t_{CLCL}-70$	ns
t_{LLDV}	2, 3	ALE low to valid data in		517		$8t_{CLCL}-150$	ns
t_{AVDV}	2, 3	Address to valid data in		585		$9t_{CLCL}-165$	ns
t_{LLWL}	2, 3	ALE low to $\overline{\text{RD}}$ or $\overline{\text{WR}}$ low	200	300	$3t_{CLCL}-50$	$3t_{CLCL}+50$	ns
t_{AVWL}	2, 3	Address valid to $\overline{\text{WR}}$ low or $\overline{\text{RD}}$ low	203		$4t_{CLCL}-130$		ns
t_{QVWX}	2, 3	Data valid to $\overline{\text{WR}}$ transition	23		$t_{CLCL}-60$		ns
t_{QVWH}	2, 3	Data valid to $\overline{\text{WR}}$ high	433		$7t_{CLCL}-150$		ns
t_{WHQX}	2, 3	Data hold after $\overline{\text{WR}}$	33		$t_{CLCL}-8$		ns
t_{RLAZ}	2, 3	$\overline{\text{RD}}$ low to address float		20		20	ns
t_{WHLH}	2, 3	$\overline{\text{RD}}$ or $\overline{\text{WR}}$ high to ALE high	43	123	$t_{CLCL}-40$	$t_{CLCL}+40$	ns
External Clock							
t_{CHCX}	5	High time	20		20		ns
t_{CLCX}	5	Low time	20		20		ns
t_{CLCH}	5	Rise time		20		20	ns
t_{CHCL}	5	Fall time		20		20	ns
Shift Register							
t_{XLXL}	4	Serial port clock cycle time	1.0		$12t_{CLCL}$		μs
t_{QVXH}	4	Output data setup to clock rising edge	700		$10t_{CLCL}-133$		ns
t_{XHQX}	4	Output data hold after clock rising edge	50		$2t_{CLCL}-117$		ns
t_{XHDX}	4	Input data hold after clock rising edge	0		0		ns
t_{XHDX}	4	Clock rising edge to input data valid		700		$10t_{CLCL}-133$	ns

NOTES:

- Parameters are valid over operating temperature range unless otherwise specified.
- Load capacitance for port 0, ALE, and $\overline{\text{PSEN}}$ = 100pF, load capacitance for all other outputs = 80pF.

EXPLANATION OF THE AC SYMBOLS

Each timing symbol has five characters. The first character is always 't' (= time). The other characters, depending on their positions, indicate the name of a signal or the logical status of that signal. The designations are:

A - Address

C - Clock

D - Input data

H - Logic level high

I - Instruction (program memory contents)

L - Logic level low, or ALE

P - $\overline{\text{PSEN}}$

Q - Output data

R - $\overline{\text{RD}}$ signal

t - Time

V - Valid

W - $\overline{\text{WR}}$ signal

X - No longer a valid logic level

Z - Float

Examples: t_{AVLL} = Time for address valid to ALE low. t_{LLPL} = Time for ALE low to $\overline{\text{PSEN}}$ low.

Single-Chip 8-Bit Microcontroller

SCN8031AH/SCN8051AH

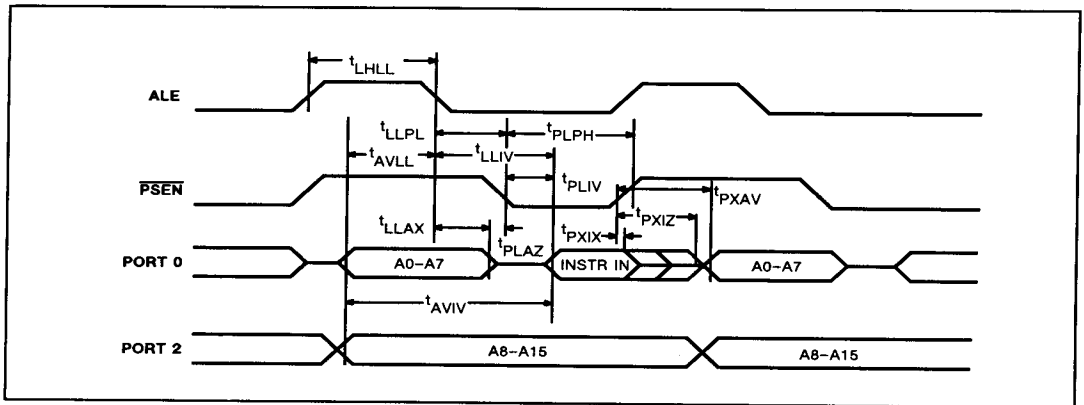


Figure 1. External Program Memory Read Cycle

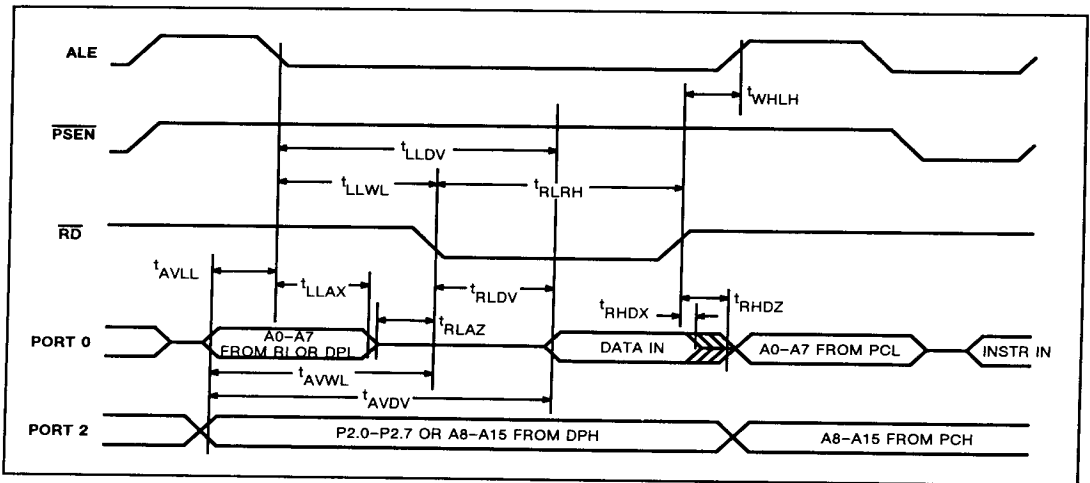


Figure 2. External Data Memory Read Cycle

Single-Chip 8-Bit Microcontroller

SCN8031AH/SCN8051AH

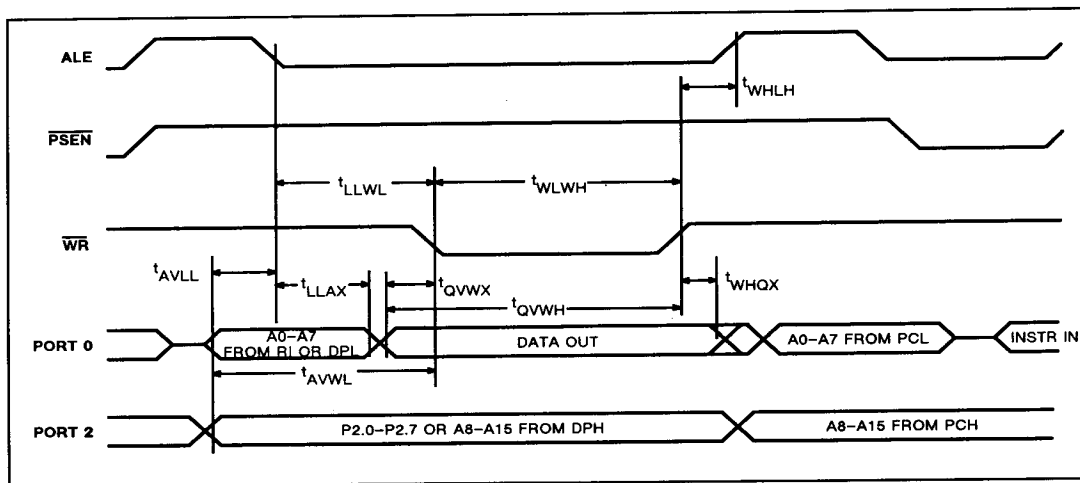


Figure 3. External Data Memory Write Cycle

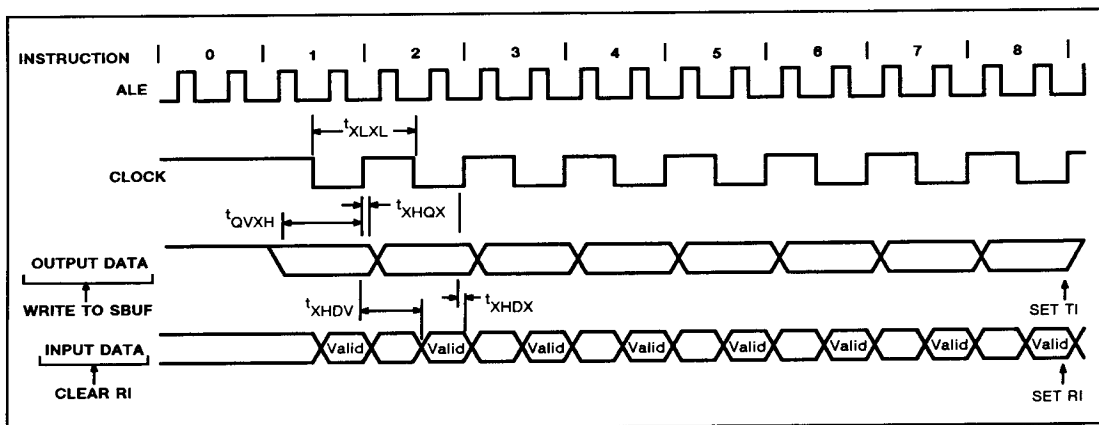


Figure 4. Shift Register Mode Timing

Single-Chip 8-Bit Microcontroller

SCN8031AH/SCN8051AH

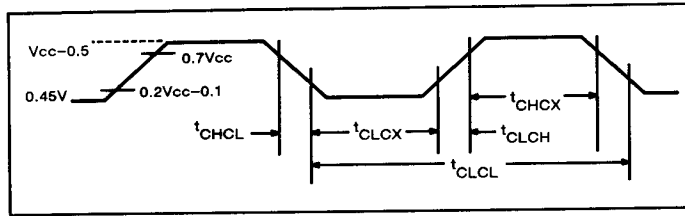


Figure 5. External Clock Drive

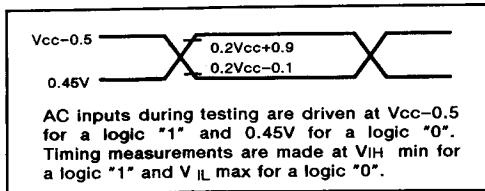


Figure 6. AC Testing Input/Output

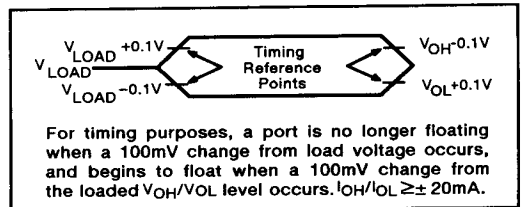


Figure 7. Float Waveform

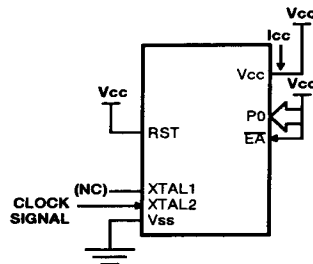


Figure 8. I_{CC} Test Condition, Active Mode
All other pins are disconnected

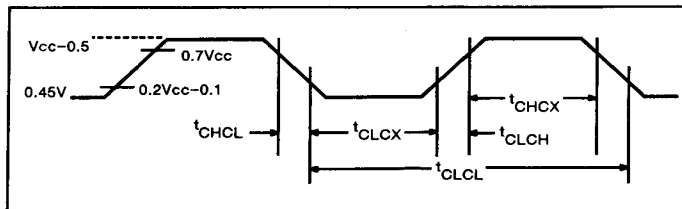


Figure 9. Clock Signal Waveform for I_{CC} Tests in Active and Idle Modes
 $t_{CLCH} = t_{CHCL} = 5ns$